# **MA3D650** (MA6D50)

## Silicon planar type (cathode common)

For high-frequency rectification

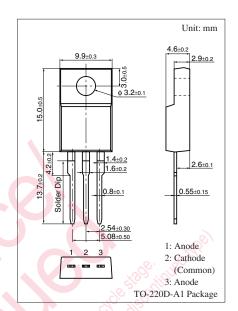
#### ■ Features

- Low forward voltage V<sub>F</sub>
- Fast reverse recovery time t<sub>rr</sub>
- TO-220D (Full-pack package) with high dielectric breakdown voltage
- Easy-to-mount, caused by its V cut lead end

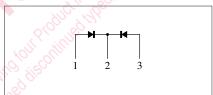
### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Repetitive peak reverse voltage	$V_{RRM}$	200	V
Non-repetitive peak reverse surge voltage	V <sub>RSM</sub>	200	v
Forward current (Average)	I <sub>F(AV)</sub>	10	A
Non-repetitive peak forward surge current *	$I_{FSM}$	60	A
Junction temperature	T <sub>j</sub>	-40 to +150	°C
Storage temperature	T <sub>stg</sub>	-40 to +150	°C

Note) \*: 50 Hz sine wave 1 cycle (Non-repetitive peak current)





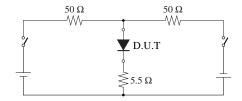


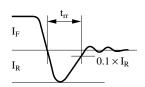
### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	$V_{\rm F}$	$I_F = 5 \text{ A}, T_C = 25^{\circ}\text{C}$			0.98	V
Repetitive peak reverse current	$I_{RRM1}$	$V_{RRM} = 200 \text{ V}, T_{C} = 25^{\circ}\text{C}$			100	μΑ
	I <sub>RRM2</sub>	$V_{RRM} = 200 \text{ V}, T_j = 150^{\circ}\text{C}$			6	mA
Reverse recovery time *	t <sub>rr</sub>	$I_F = 1 \text{ A}, I_R = 1 \text{ A}$			30	ns
Thermal resistance (j-c)	R <sub>th(j-c)</sub>				3.0	°C/W
Thermal resistance (j-a)	R <sub>th(j-a)</sub>				63	°C/W

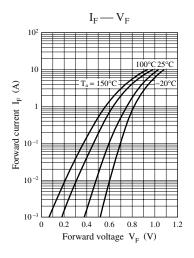
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

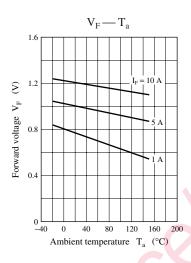
- 2. Absolute frequency of input and output is 10 MHz.
- 3. \*: t<sub>rr</sub> measurement circuit

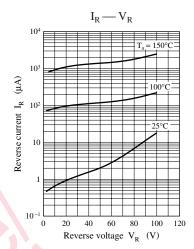


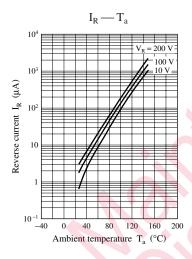


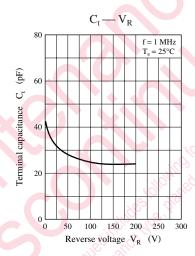
Note) The part number in the parenthesis shows conventional part number.

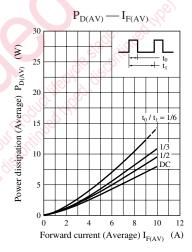


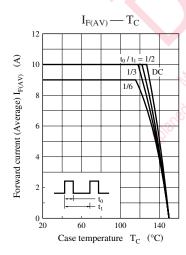












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